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Serial No. 10/751,257 Infineon Ref No. P26950 OC Ref No. 10808/121

# DECLARATION FOR PATENT APPLICATION, POWER OF ATTORNEY & DESIGNATION OF CORRESPONDENCE ADDRESS

As below named inventor, I hereby declare that:

VJP MUNICH

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

# METHOD OF MANUFACTURING A LAYER SEQUENCE AND A METHOD OF

•	MANUFACTU	RING AN INTEGRATED CIRC	JU[1			
the specification of	of which (check one	9)				
is attache	ed hereto.					
X was filed on January 2, 2004 as Application Serial No. 10/751,257						
and was amended on (if applicable).						
I hereby identified specific above.	state that I have cation including the	reviewed and understand the claims, as amended by an	e contents of ly amendment	the above- referred to		
		isclose information known to ordance with 37 CFR §1.56(a		terial to the		
	OR TO THIS APPL	ON(S) FILED WITHIN 12 MC ICATION AND ANY PRIORIT U.S.C. § 119(a)-(d)				
I hereby claim foreign priority benefits under 35 USC § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:						
Prior Foreign Application(s)			Priority (	Claimed		
Number	Country	Day/Month/Year Filed	Yes	No		

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## CLAIM FOR BENEFIT OF PRIOR U.S. PROVISIONAL APPLICATION(S) (35 U.S.C. § 119(e))

I hereby claim the benefit under Title 35. United States Code, § 119 (e) of any United States provisional application(s) listed below:

Filing Date

## CLAIM FOR BENEFIT OF EARLIER US/PCT APPLICATION(S) UNDER 35 U.S.C. § 120

I hereby claim the benefits under 35 USC § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 USC § 112. I acknowledge the duty to disclose material information as defined in 37 CFR § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Appl. No.	Filing Date	Patented, Pending, Abandoned	

Power of Attorney: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

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I hereby declare that all statements made herein on my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both under 18 USC §1001 and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

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